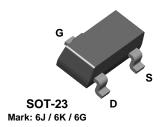


PN4391 PN4392 PN4393 MMBF4391 MMBF4392 **MMBF4393**





NOTE: Source & Drain are interchangeable

N-Channel Switch

This device is designed for low level analog switching, sample and hold circuits and chopper stabalized amplifiers. Sourced from Process 51. See J111 for characteristics.

Absolute Maximum Ratings* TA = 25°C unless otherwise noted

Symbol	Parameter	Value	Units	
V_{DG}	Drain-Gate Voltage	30	V	
V _{GS}	Gate-Source Voltage	- 30	V	
I _{GF}	Forward Gate Current	50	mA	
T _J ,T _{stg}	Operating and Storage Junction Temperature Range	-55 to +150	°C	

^{*}These ratings are limiting values above which the serviceability of any semiconductor device may be impaired.

Thermal Characteristics TA = 25°C unless otherwise noted

Symbol	Characteristic	N	Units	
		PN4391-4393	*MMBF4391-4393	
P_D	Total Device Dissipation Derate above 25°C	625 5.0	350 2.8	mW mW/°C
$R_{\theta JC}$	Thermal Resistance, Junction to Case	125		°C/W
$R_{\theta JA}$	Thermal Resistance, Junction to Ambient	357	556	°C/W

^{*}Device mounted on FR-4 PCB 1.6" X 1.6" X 0.06."

¹⁾ These ratings are based on a maximum junction temperature of 150 degrees C.

2) These are steady state limits. The factory should be consulted on applications involving pulsed or low duty cycle operations

N-Channel Switch (continued)

Symbol	Parameter		Min	Max	Units	
OFF CHAF	RACTERISTICS					
V _{(BR)GSS}	Gate-Source Breakdown Voltage	$I_G = 1.0 \mu A, V_{DS} = 0$		- 30		V
I _{GSS}	Gate Reverse Current	V _{GS} = - 15 V, V _{DS} = 0			- 1.0	nA
1000		$V_{GS} = -15 \text{ V}, V_{DS} = 0, T_A = 0$	150°C		- 0.2	μA
V _{GS(off)}	Gate-Source Cutoff Voltage	$V_{DS} = 20 \text{ V}, I_{D} = 1.0 \text{ nA}$	4391	- 4.0	- 10	·V
			4392	- 2.0	- 5.0	V
\ /	Cotto Conses Francis IV allege	1 1 2 3 4 2 4 2	4393	- 0.5	- 3.0	V
V _{GS(f)}	Gate-Source Forward Voltage	$I_G = 1.0 \text{ mA}, V_{DS} = 0$			1.0	V
I _{D(off)}	Drain Cutoff Leakage Current	V _{DS} = 20 V, V _{GS} = -12 V	4391		0.1	nA
		$V_{DS} = 20 \text{ V}, V_{GS} = -7.0 \text{ V}$ $V_{DS} = 20 \text{ V}, V_{GS} = -5.0 \text{ V}$	4392 4393		0.1 0.1	nA nA
		V _{DS} = 20 V, V _{GS} = -3.0 V V _{DS} = 20 V, V _{GS} = -12 V,	4333		0.1	11/4
		$T_A = 150^{\circ}C$	4391		0.2	μΑ
		$V_{DS} = 20 \text{ V}, V_{GS} = -7.0 \text{ V},$				
		T _A = 150°C	4392		0.2	μΑ
		$V_{DS} = 20 \text{ V}, V_{GS} = -5.0 \text{ V},$	4000		0.2	μА
		T _A = 150°C	4393		0.2	μΑ
ON CHARA	ACTERISTICS					
I _{DSS}	Zero-Gate Voltage Drain Current*	$V_{DS} = 20 \text{ V}, V_{GS} = 0$	4391	50	150	mA
			4392	25	75	mA
			4393	5.0	30	mA
$V_{DS(on)}$	Drain-Source On Voltage	$I_D = 12 \text{ mA}, V_{GS} = 0$	4391		0.4	V
		$I_D = 6.0 \text{ mA}, V_{GS} = 0$	4392		0.4	V
_	Drain-Source On Resistance	$I_D = 3.0 \text{ mA}, V_{GS} = 0$	4393		0.4	V
r _{DS(on)}	Drain-Source On Resistance	$I_D = 1.0 \text{ mA}, V_{GS} = 0$	4391 4392		30 60	Ω
			4393		100	Ω
CMALL CI	GNAL CHARACTERISTICS	•				
r _{ds(on)}	Drain-Source On Resistance	$V_{DS} = V_{GS} = 0$, f= 1.0 kHz	4391		30	Ω
rus(on)		1 50 1 60 0,1 110 111 12	4392		60	Ω
			4393		100	Ω
Ciss	Input Capacitance	$V_{DS} = 20, V_{GS} = 0, f = 1.0 M$	Hz		14	pF
C _{rss}	Reverse Transfer Capacitance	V _{GS} = - 12 V, f = 1.0 MHz	4391		3.5	pF
		$V_{GS} = -7.0 \text{ V}, f = 1.0 \text{ MHz}$	4392		3.5	pF
		$V_{GS} = -5.0 \text{ V}, f = 1.0 \text{ MHz}$	4393		3.5	pF
SWITCHIN	NG CHARACTERISTICS					
t _r	Rise Time	I _{D(on)} = 12 mA	4391		5.0	ns
		$I_{D(on)} = 6.0 \text{ mA}$	4392		5.0	ns
		$I_{D(on)} = 3.0 \text{ mA}$	4393		5.0	ns
t _f	Fall Time	V _{GS(off)} = 12 V	4391		15	ns
		$V_{GS(off)} = 6.0 \text{ V}$	4392		20	ns
		$V_{GS(off)} = 3.0 \text{ V}$	4393		30	ns
ton	Turn-On Time	$I_{D(on)} = 12 \text{ mA}$	4391		15	ns
		$I_{D(on)} = 6.0 \text{ mA}$	4392		15	ns
		$I_{D(on)} = 3.0 \text{ mA}$	4393		15	ns
t _{off}	Turn-Off Time	$V_{GS(off)} = 12 V$	4391		20	ns
		$V_{GS(off)} = 6.0 \text{ V}$	4392		35 50	ns ns
	Í	$V_{GS(off)} = 3.0 \text{ V}$	4393		50	115

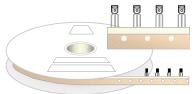
*Pulse Test: Pulse Width \leq 300 μ s, Duty Cycle \leq 1.0%

TO-92 Tape and Reel Data FAIRCHILD SEMICONDUCTOR TM **TO-92 Packaging** Configuration: Figure 1.0 **TAPE and REEL OPTION** FSCINT Label sample See Fig 2.0 for various Reeling Styles CBVK//418019 **FSCINT** Label 5 Reels per Intermediate Box Customized F63TNR Label sample Label F63TNR LOT: CBVK741B019 QTY: 2000 FSID: PN222N Customized QTY1: QTY2: Label 375mm x 267mm x 375mm Intermediate Box TO-92 TNR/AMMO PACKING INFROMATION **AMMO PACK OPTION** See Fig 3.0 for 2 Ammo Packing Style Quantity EOL code **Pack Options** 2,000 D26Z Е 2,000 D27Z Ammo М 2,000 D74Z D75Z 2,000 **FSCINT** Unit weight = 0.22 gm Reel weight with components = 1.04 kg Ammo weight with components = 1.02 kg Max quantity per intermediate box = 10,000 units Label 5 Ammo boxes per Intermediate Box 327mm x 158mm x 135mm Immediate Box Customized F63TNR Customized Label Label 333mm x 231mm x 183mm Intermediate Box (TO-92) BULK PACKING INFORMATION **BULK OPTION** See Bulk Packing DESCRIPTION QUANTITY Information table J18Z TO-18 OPTION STD 2.0 K / BOX Anti-static Bubble Sheets TO-5 OPTION STD NO LEAD CLIP 1.5 K / BOX J05Z **FSCINT Label** NO EOL TO-92 STANDARD STRAIGHT FOR: PKG 92, NO LEADCLIP 2.0 K / BOX 94 (NON PROELECTRON SERIES), 96 TO-92 STANDARD STRAIGHT FOR: PKG 94 (PROELECTRON SERIES BCXXX, BFXXX, BSRXXX), 97, 98 L34Z NO LEADCLIP 2.0 K / BOX 2000 units per 114mm x 102mm x 51mm EO70 box for std option Immediate Box 5 EO70 boxes per intermediate Box 530mm x 130mm x 83mm Customized Intermediate box Label FSCINT Label 10,000 units maximum per intermediate box for std option

TO-92 Tape and Reel Data, continued

TO-92 Reeling Style Configuration: Figure 2.0

Machine Option "A" (H)

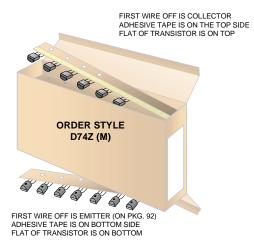


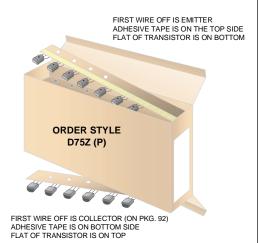
Style "A", D26Z, D70Z (s/h)

Machine Option "E" (J)

Style "E", D27Z, D71Z (s/h)

TO-92 Radial Ammo Packaging Configuration: Figure 3.0





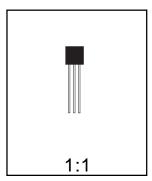


TO-92 Package Dimensions



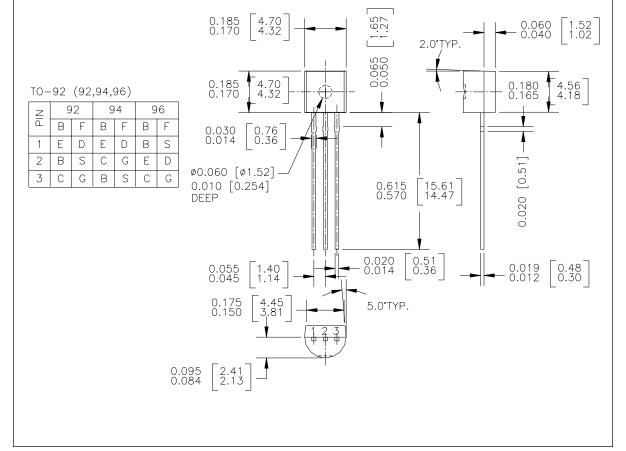
TO-92 (FS PKG Code 92, 94, 96)

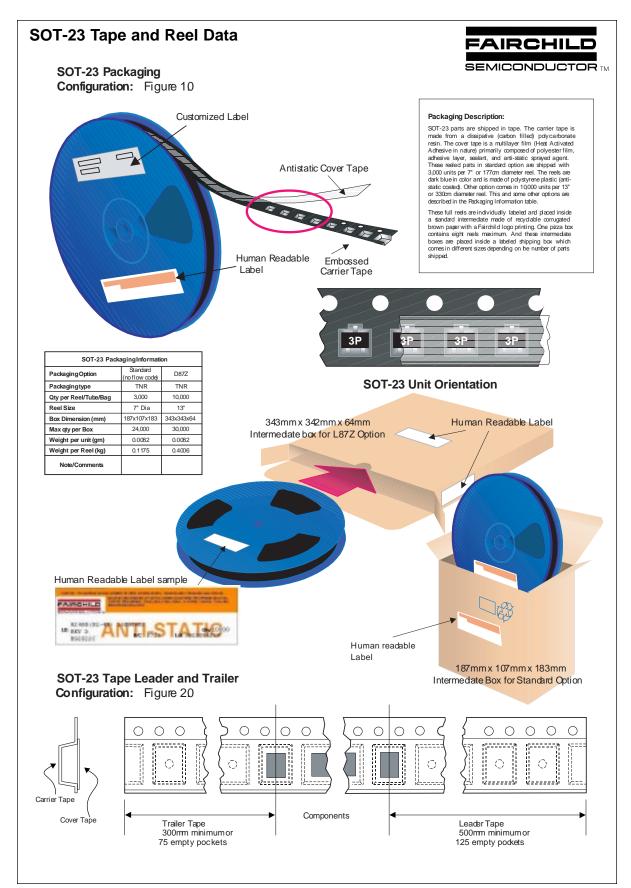




Scale 1:1 on letter size paper
Dimensions shown below are in:
inches [millimeters]

Part Weight per unit (gram): 0.1977

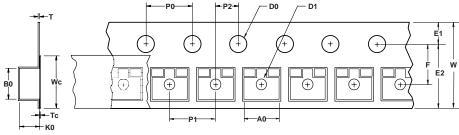




SOT-23 Tape and Reel Data, continued

SOT-23 Embossed Carrier Tape

Configuration: Figure 3.0



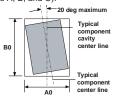
User Direction of Feed

	Dimensions are in millimeter													
Pkg type	Α0	В0	w	D0	D1	E1	E2	F	P1	P0	K0	Т	Wc	Тс
SOT-23 (8mm)	3.15 +/-0.10	2.77 +/-0.10	8.0 +/-0.3	1.55 +/-0.05	1.125 +/-0.125	1.75 +/-0.10	6.25 min	3.50 +/-0.05	4.0 +/-0.1	4.0 +/-0.1	1.30 +/-0.10	0.228 +/-0.013	5.2 +/-0.3	0.06 +/-0.02

Notes: A0, B0, and K0 dimensions are determined with respect to the EIA/Jedec RS-481 rotational and lateral movement requirements (see sketches A, B, and C).



Sketch A (Side or Front Sectional View)
Component Rotation

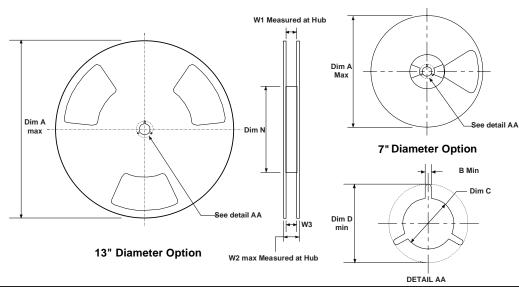


Sketch B (Top View)
Component Rotation



Sketch C (Top View)
Component lateral movement

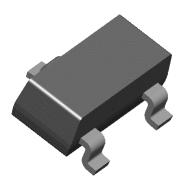
SOT-23 Reel Configuration: Figure 4.0

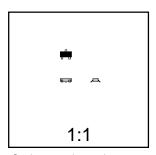


	Dimensions are in inches and millimeters								
Tape Size	Reel Option	Dim A	Dim B	Dim C	Dim D	Dim N	Dim W1	Dim W2	Dim W3 (LSL-USL)
8mm	7" Dia	7.00 177.8	0.059 1.5	512 +0.020/-0.008 13 +0.5/-0.2	0.795 20.2	2.165 55	0.331 +0.059/-0.000 8.4 +1.5/0	0.567 14.4	0.311 - 0.429 7.9 - 10.9
8mm	13" Dia	13.00 330	0.059 1.5	512 +0.020/-0.008 13 +0.5/-0.2	0.795 20.2	4.00 100	0.331 +0.059/-0.000 8.4 +1.5/0	0.567 14.4	0.311 - 0.429 7.9 - 10.9



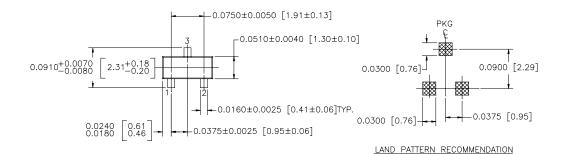
SOT-23 (FS PKG Code 49)

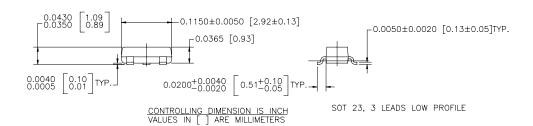




Scale 1:1 on letter size paper Dimensions shown below are in:

inches [millimeters]
Part Weight per unit (gram): 0.0082





NOTE: UNLESS OTHERWISE SPECIFIED

- 1. STANDARD LEAD FINISH 150 MICROINCHES / 3.81 MICROMETERS MINIMUM TIN / LEAD (SOLDER) ON ALLOY 42
- 2. REFERENCE JEDEC REGISTRATION TO-236, VARIATION AB, ISSUE G, DATED JUL 1993

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